

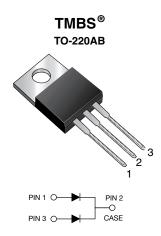
Vishay General Semiconductor

COMPLIANT

HALOGEN

FREE

Dual High Voltage Trench MOS Barrier Schottky Rectifier



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 10 A			
V _{RRM}	90 V, 100 V			
I _{FSM}	150 A			
V _F	0.65 V			
T _J max.	150 °C			
Package	TO-220AB			
Diode variation	Common cathode			

FEATURES

- Trench MOS Schottky technology
- Lower power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- High frequency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters or polarity protection application.

MECHANICAL DATA

Case: TO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and

commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs max.

PARAMETER		SYMBOL	MBR2090CT	MBR20100CT	UNIT
Max. repetitive peak reverse voltage		V_{RRM}	90	100	V
Working peak reverse voltage		V _{RWM}	90	100	V
Max. DC blocking voltage		V_{DC}	90	100	V
Max. average forward rectified current at T _C = 133 °C	total device		20 10		А
	per diode	I _{F(AV)}			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	150		А
Voltage rate of change (rated V _R)		dV/dt	10 000		V/µs
Operating junction and storage temperature range		T _J , T _{STG}	-65 to +150		°C

MBR2090CT-M3, MBR20100CT-M3

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ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT	
	I _E = 10 A	T _C = 25 °C		0.80		
Max. instantaneous forward voltage per diode	I _F = 10 A	T _C = 125 °C	V _F ⁽¹⁾	0.65	V	
	I _F = 20 A			0.75		
maxi reverse carrent per alcae	T _J = 25 °C	I _R ⁽²⁾	100	μΑ		
		T _J = 100 °C	IR (=)	6.0	mA	

Notes

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS						
PARAMETER	SYMBOL	SYMBOL MBR2090CT, MBR20100CT				
Typical thermal registance per diede	$R_{ hetaJA}$	60	°C/W			
Typical thermal resistance per diode	$R_{ heta JC}$	2.0	C/VV			

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-220AB	MBR20100CT-M3/4W	1.88	4W	50/tube	Tube	

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

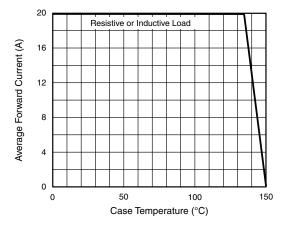


Fig. 1 - Forward Current Derating Curve

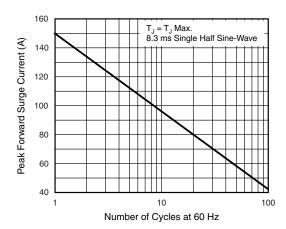


Fig. 2 - Max. Non-Repetitive Peak Forward Surge Current Per Diode

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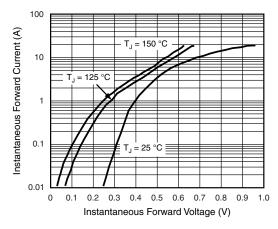


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

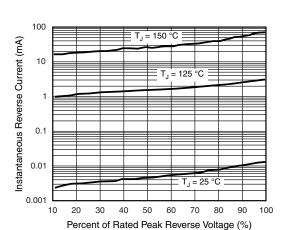


Fig. 4 - Typical Reverse Characteristics Per Diode

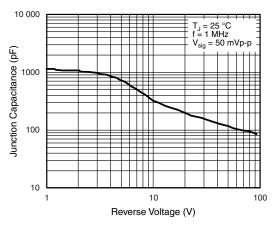


Fig. 5 - Typical Junction Capacitance Per Diode

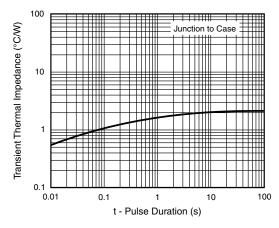
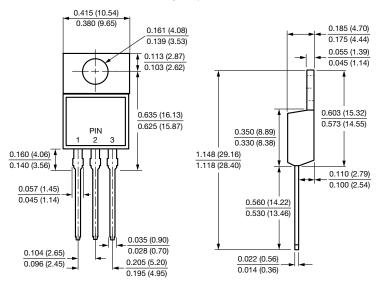


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-220AB





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